

# Sheng Wang

## List of Publications by Year in descending order

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110  
papers

5,200  
citations

87888

38  
h-index

91884

69  
g-index

113  
all docs

113  
docs citations

113  
times ranked

5803  
citing authors

#	ARTICLE	IF	CITATIONS
1	Branched Anion-Conducting Poly(arylene alkylene)s for Alkaline Membrane Fuel Cells. ACS Applied Energy Materials, 2022, 5, 2462-2473.	5.1	27
2	Self-Reporting Activated Ester-Amine Reaction for Enantioselective Multi-Channel Visual Detection of Chiral Amines. Angewandte Chemie - International Edition, 2022, 61, .	13.8	34
3	Allostery-Mimicking Self-assembly of Helical Poly(phenylacetylene) Block Copolymers and the Chirality Transfer. Angewandte Chemie - International Edition, 2021, 60, 9686-9692.	13.8	51
4	Allostery-Mimicking Self-assembly of Helical Poly(phenylacetylene) Block Copolymers and the Chirality Transfer. Angewandte Chemie, 2021, 133, 9772-9778.	2.0	10
5	Field-effect at electrical contacts to two-dimensional materials. Nano Research, 2021, 14, 4894-4900.	10.4	11
6	Brightening up Circularly Polarized Luminescence of Monosubstituted Polyacetylene by Conformation Control: Mechanism, Switching, and Sensing. Angewandte Chemie, 2021, 133, 22089-22097.	2.0	20
7	Brightening up Circularly Polarized Luminescence of Monosubstituted Polyacetylene by Conformation Control: Mechanism, Switching, and Sensing. Angewandte Chemie - International Edition, 2021, 60, 21918-21926.	13.8	82
8	Hf-Contacted High-Performance Air-Stable n-Type Carbon Nanotube Transistors. ACS Applied Electronic Materials, 2021, 3, 4623-4629.	4.3	10
9	Photodetector based on heterostructure of two-dimensional WSe <sub>2</sub> /In <sub>2</sub> Se <sub>3</sub> . Nanotechnology, 2020, 31, 065203.	2.6	41
10	Silicon-Waveguide-Integrated Carbon Nanotube Optoelectronic System on a Single Chip. ACS Nano, 2020, 14, 7191-7199.	14.6	30
11	Doublet Chirality Transfer and Reversible Helical Transition in Poly(3,5-disubstituted) Tj ETQq1 1 0.784314 rgBT /Overlock 10 Tf 50 34 570-576.	4.9	9
12	Tunable Cis-cisoid Helical Conformation of Poly(3,5-disubstituted phenylacetylene)s Stabilized by nâ†’î€* Interaction. Chinese Journal of Polymer Science (English Edition), 2020, 38, 685-695.	3.8	8
13	Polymerization-Induced Self-Assembly of Conjugated Block Copoly(phenylacetylene)s. Macromolecules, 2020, 53, 1638-1644.	4.8	41
14	Improving the Performance and Uniformity of Carbon-Nanotube-Network-Based Photodiodes via Yttrium Oxide Coating and Decoating. ACS Applied Materials & Interfaces, 2019, 11, 11736-11742.	8.0	26
15	Carbon nanotube-based photovoltaic receiver with open-circuit voltage larger than 10â€V. Nano Energy, 2019, 57, 241-247.	16.0	4
16	<i>Cis-Cisoid</i> Helical Structures of Poly(3,5-disubstituted phenylacetylene)s Stabilized by Intramolecular n â†’ î€* Interactions. Macromolecules, 2018, 51, 1251-1259.	4.8	34
17	Switching Vertical to Horizontal Graphene Growth Using Faraday Cage-Assisted PECVD Approach for High-Performance Transparent Heating Device. Advanced Materials, 2018, 30, 1704839.	21.0	62
18	Amphiphilic Rod-Rod Block Copolymers Based on Phenylacetylene and 3,5-Disubstituted Phenylacetylene: Synthesis, Helical Conformation, and Self-Assembly. Macromolecules, 2018, 51, 7500-7508.	4.8	24

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19	Plasmon-Induced Enhancement of Infrared Detection Using a Carbon Nanotube Diode. <i>Advanced Optical Materials</i> , 2017, 5, 1600865.	7.3	9
20	Microcavity-Controlled Chirality-Sorted Carbon Nanotube Film Infrared Light Emitters. <i>ACS Photonics</i> , 2017, 4, 435-442.	6.6	14
21	Planar-to-Axial Chirality Transfer in the Polymerization of Phenylacetylenes. <i>ACS Macro Letters</i> , 2017, 6, 205-209.	4.8	14
22	Conformation Shift Switches the Chiral Amplification of Helical Copoly(phenylacetylene)s from Abnormal to Normal "Sergeants-and-Soldiers" Effect. <i>Macromolecules</i> , 2017, 50, 4610-4615.	4.8	63
23	Carbon nanotube-based three-dimensional monolithic optoelectronic integrated system. <i>Nature Communications</i> , 2017, 8, 15649.	12.8	57
24	Plasmonic Enhanced Performance of an Infrared Detector Based on Carbon Nanotube Films. <i>ACS Applied Materials &amp; Interfaces</i> , 2017, 9, 12743-12749.	8.0	28
25	Asymmetric Light Excitation for Photodetectors Based on Nanoscale Semiconductors. <i>ACS Nano</i> , 2017, 11, 549-557.	14.6	10
26	Electrically driven monolithic subwavelength plasmonic interconnect circuits. <i>Science Advances</i> , 2017, 3, e1701456.	10.3	34
27	Performance improvement induced by asymmetric Y2O3-coated device structure to carbon-nanotube-film based photodetectors. <i>Applied Physics Letters</i> , 2017, 111, .	3.3	5
28	Electrostatics and quantum efficiency simulations of asymmetrically contacted carbon nanotube photodetector. <i>AIP Advances</i> , 2017, 7, 105111.	1.3	0
29	Toward High-Performance Carbon Nanotube Photovoltaic Devices. <i>Advanced Energy Materials</i> , 2016, 6, 1600522.	19.5	28
30	Microcavity-Integrated Carbon Nanotube Photodetectors. <i>ACS Nano</i> , 2016, 10, 6963-6971.	14.6	36
31	Acoustic-assisted assembly of an individual monochromatic ultralong carbon nanotube for high on-current transistors. <i>Science Advances</i> , 2016, 2, e1601572.	10.3	32
32	On-chip polarized light emitters based on (6,5) chirality-sorted carbon nanotube aligned arrays. <i>Applied Physics Letters</i> , 2016, 108, .	3.3	9
33	Photovoltaic Devices: Toward High-Performance Carbon Nanotube Photovoltaic Devices (Adv. Energy) Tj ETQq1 1 0,784314 rgBT /Overl	19.5	28
34	Contact-dominated transport in carbon nanotube thin films: toward large-scale fabrication of high performance photovoltaic devices. <i>Nanoscale</i> , 2016, 8, 17122-17130.	5.6	11
35	High Conversion Efficiency Carbon Nanotube-Based Barrier-Free Bipolar-Diode Photodetector. <i>ACS Nano</i> , 2016, 10, 9595-9601.	14.6	23
36	Reversible <i>Cis-Cisoid</i> to <i>Cis-Transoid</i> Helical Structure Transition in Poly(3,5-disubstituted phenylacetylene)s. <i>Macromolecules</i> , 2016, 49, 8407-8417.	4.8	59

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37	Nanoscale color sensors made on semiconducting multi-wall carbon nanotubes. Nano Research, 2016, 9, 1470-1479.	10.4	6
38	Room Temperature Broadband Infrared Carbon Nanotube Photodetector with High Detectivity and Stability. Advanced Optical Materials, 2016, 4, 238-245.	7.3	90
39	Photodetectors: Room Temperature Broadband Infrared Carbon Nanotube Photodetector with High Detectivity and Stability (Advanced Optical Materials 2/2016). Advanced Optical Materials, 2016, 4, 188-188.	7.3	2
40	Controllable Sliding Transfer of Wafer-Size Graphene. Advanced Science, 2016, 3, 1600006.	11.2	25
41	Solid state carbon nanotube device for controllable trion electroluminescence emission. Nanoscale, 2016, 8, 6761-6769.	5.6	20
42	Flexible Light-Emitting Devices Based on Chirality-Sorted Semiconducting Carbon Nanotube Films. ACS Applied Materials & Interfaces, 2015, 7, 3462-3467.	8.0	19
43	Room temperature infrared imaging sensors based on highly purified semiconducting carbon nanotubes. Nanoscale, 2015, 7, 6805-6812.	5.6	16
44	Electroluminescence from Serpentine Carbon Nanotube Based Light-Emitting Diodes on Quartz. Small, 2014, 10, 1050-1056.	10.0	13
45	Scalable Fabrication of Ambipolar Transistors and Radio-Frequency Circuits Using Aligned Carbon Nanotube Arrays. Advanced Materials, 2014, 26, 645-652.	21.0	30
46	Modularized Construction of General Integrated Circuits on Individual Carbon Nanotubes. Nano Letters, 2014, 14, 3102-3109.	9.1	28
47	Growth of Semiconducting Single-Walled Carbon Nanotubes by Using Ceria as Catalyst Supports. Nano Letters, 2014, 14, 512-517.	9.1	80
48	Carbon nanotube electronics: recent advances. Materials Today, 2014, 17, 433-442.	14.2	267
49	Length Scaling of Carbon Nanotube Electric and Photo Diodes down to Sub-50 nm. Nano Letters, 2014, 14, 5382-5389.	9.1	25
50	Carbon nanotube light sensors with linear dynamic range of over 120-dB. Applied Physics Letters, 2014, 105, .	3.3	29
51	Photoelectric Characteristics of Self-Assembled Semiconducting Carbon Nanotube Thin Films. Wuli Huaxue Xuebao/ Acta Physico - Chimica Sinica, 2014, 30, 1377-1383.	4.9	0
52	Breakdown of Richardson's Law in Electron Emission from Individual Self-Joule-Heated Carbon Nanotubes. Scientific Reports, 2014, 4, 5102.	3.3	28
53	Batch-fabricated high-performance graphene Hall elements. Scientific Reports, 2013, 3, 1207.	3.3	72
54	Plasmonic enhancement of photocurrent in carbon nanotube by Au nanoparticles. Applied Physics Letters, 2013, 102, .	3.3	34

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55	Carbon Nanotube Photoelectronic and Photovoltaic Devices and their Applications in Infrared Detection. <i>Small</i> , 2013, 9, 1225-1236.	10.0	92
56	Surface modification effect on photoluminescence of individual ZnO nanorods with different diameters. <i>Nanoscale</i> , 2013, 5, 4443.	5.6	30
57	Direct observation of substrate induced exciton in carbon nanotube. <i>Applied Physics Letters</i> , 2013, 103, .	3.3	1
58	Carbon Nanotube Based Multifunctional Ambipolar Transistors for AC Applications. <i>Advanced Functional Materials</i> , 2013, 23, 446-450.	14.9	11
59	Helicity-dependent single-walled carbon nanotube alignment on graphite for helical angle and handedness recognition. <i>Nature Communications</i> , 2013, 4, 2205.	12.8	45
60	High-mobility graphene on liquid p-block elements by ultra-low-loss CVD growth. <i>Scientific Reports</i> , 2013, 3, 2670.	3.3	75
61	CMOS-based carbon nanotube pass-transistor logic integrated circuits. <i>Nature Communications</i> , 2012, 3, 677.	12.8	145
62	Electrical transport properties of individual WS <sub>2</sub> nanotubes and their dependence on water and oxygen absorption. <i>Applied Physics Letters</i> , 2012, 101, .	3.3	42
63	A doping-free approach to carbon nanotube electronics and optoelectronics. <i>AIP Advances</i> , 2012, 2, .	1.3	25
64	Carbon nanotube arrays based high-performance infrared photodetector [Invited]. <i>Optical Materials Express</i> , 2012, 2, 839.	3.0	93
65	Carbon Nanotube Field-Effect Transistors for Use as Pass Transistors in Integrated Logic Gates and Full Subtractor Circuits. <i>ACS Nano</i> , 2012, 6, 4013-4019.	14.6	22
66	Contact length scaling in graphene field-effect transistors. <i>Applied Physics Letters</i> , 2012, 100, 103501.	3.3	32
67	High-performance photodetectors for visible and near-infrared lights based on individual WS <sub>2</sub> nanotubes. <i>Applied Physics Letters</i> , 2012, 100, .	3.3	111
68	Channel-Length-Dependent Transport and Photovoltaic Characteristics of Carbon-Nanotube-Based, Barrier-Free Bipolar Diode. <i>ACS Applied Materials &amp; Interfaces</i> , 2012, 4, 1154-1157.	8.0	9
69	Carbon nanotube based ultra-low voltage integrated circuits: Scaling down to 0.4 V. <i>Applied Physics Letters</i> , 2012, 100, 263116.	3.3	61
70	High-performance doping-free carbon-nanotube-based CMOS devices and integrated circuits. <i>Science Bulletin</i> , 2012, 57, 135-148.	1.7	14
71	Doping-free carbon nanotube optoelectronic devices. <i>Science Bulletin</i> , 2012, 57, 149-156.	1.7	23
72	Doping-free fabrication of carbon nanotube thin-film diodes and their photovoltaic characteristics. <i>Nano Research</i> , 2012, 5, 33-42.	10.4	12

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73	Structure and optical properties of individual hierarchical ZnS nanobelt/ZnO nanorod heterostructures. <i>CrystEngComm</i> , 2011, 13, 6774.	2.6	14
74	High-Performance Carbon Nanotube Light-Emitting Diodes with Asymmetric Contacts. <i>Nano Letters</i> , 2011, 11, 23-29.	9.1	91
75	Electronic transport in single-walled carbon nanotube/graphene junction. <i>Applied Physics Letters</i> , 2011, 99, .	3.3	48
76	Rational design of a binary metal alloy for chemical vapour deposition growth of uniform single-layer graphene. <i>Nature Communications</i> , 2011, 2, 522.	12.8	223
77	Top-Gated Graphene Field-Effect Transistors with High Normalized Transconductance and Designable Dirac Point Voltage. <i>ACS Nano</i> , 2011, 5, 5031-5037.	14.6	96
78	Self-Aligned U-Gate Carbon Nanotube Field-Effect Transistor with Extremely Small Parasitic Capacitance and Drain-Induced Barrier Lowering. <i>ACS Nano</i> , 2011, 5, 2512-2519.	14.6	32
79	Emission Red Shift and Temperature Increase in Electrically Powered ZnO Nanowires. <i>Journal of Physical Chemistry C</i> , 2011, 115, 8283-8287.	3.1	5
80	Quantum Capacitance Limited Vertical Scaling of Graphene Field-Effect Transistor. <i>ACS Nano</i> , 2011, 5, 2340-2347.	14.6	128
81	Efficient photovoltage multiplication in carbon nanotubes. <i>Nature Photonics</i> , 2011, 5, 672-676.	31.4	133
82	Hysteresis-free HfO <sub>2</sub> film grown by atomic layer deposition at low temperature. <i>Thin Solid Films</i> , 2011, 519, 7723-7726.	1.8	6
83	Temperature Performance of Doping-Free Top-Gate CNT Field-Effect Transistors: Potential for Low- and High-Temperature Electronics. <i>Advanced Functional Materials</i> , 2011, 21, 1843-1849.	14.9	24
84	Ultrahigh secondary electron emission of carbon nanotubes. <i>Applied Physics Letters</i> , 2010, 96, .	3.3	22
85	Growth and Performance of Yttrium Oxide as an Ideal High- $\kappa$ Gate Dielectric for Carbon-Based Electronics. <i>Nano Letters</i> , 2010, 10, 2024-2030.	9.1	137
86	Large Signal Operation of Small Band-Gap Carbon Nanotube-Based Ambipolar Transistor: A High-Performance Frequency Doubler. <i>Nano Letters</i> , 2010, 10, 3648-3655.	9.1	36
87	A high-performance top-gate graphene field-effect transistor based frequency doubler. <i>Applied Physics Letters</i> , 2010, 96, .	3.3	113
88	Y-Contacted High-Performance n-Type Single-Walled Carbon Nanotube Field-Effect Transistors: Scaling and Comparison with Sc-Contacted Devices. <i>Nano Letters</i> , 2009, 9, 4209-4214.	9.1	150
89	Towards Entire-Carbon-Nanotube Circuits: The Fabrication of Single-Walled-Carbon-Nanotube Field-Effect Transistors with Local Multiwalled-Carbon-Nanotube Interconnects. <i>Advanced Materials</i> , 2009, 21, 1339-1343.	21.0	31
90	Almost Perfectly Symmetric SWCNT-Based CMOS Devices and Scaling. <i>ACS Nano</i> , 2009, 3, 3781-3787.	14.6	100

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91	Photovoltaic Effects in Asymmetrically Contacted CNT Barrier-Free Bipolar Diode. <i>Journal of Physical Chemistry C</i> , 2009, 113, 6891-6893.	3.1	45
92	A Doping-Free Carbon Nanotube CMOS Inverter-Based Bipolar Diode and Ambipolar Transistor. <i>Advanced Materials</i> , 2008, 20, 3258-3262.	21.0	66
93	Self-Aligned Ballistic n-Type Single-Walled Carbon Nanotube Field-Effect Transistors with Adjustable Threshold Voltage. <i>Nano Letters</i> , 2008, 8, 3696-3701.	9.1	154
94	Measuring the electrical characteristics of individual junctions in the SnO <sub>2</sub> capped ZnO nanowire arrays on Zn substrate. <i>Applied Physics Letters</i> , 2008, 92, 033102.	3.3	8
95	Self-Retracting Motion of Graphite Microflakes. <i>Physical Review Letters</i> , 2008, 100, 067205.	7.8	193
96	High-performance n-type carbon nanotube field-effect transistors with estimated sub-10-ps gate delay. <i>Applied Physics Letters</i> , 2008, 92, 133117.	3.3	67
97	A Comparative Study on SWCNT and DWCNT Field-Effect Transistors. <i>Journal of Nanoscience and Nanotechnology</i> , 2007, 7, 1568-1572.	0.9	9
98	Fabrication of high performance top-gate complementary inverter using a single carbon nanotube and via a simple process. <i>Applied Physics Letters</i> , 2007, 90, 223116.	3.3	21
99	Doping-Free Fabrication of Carbon Nanotube Based Ballistic CMOS Devices and Circuits. <i>Nano Letters</i> , 2007, 7, 3603-3607.	9.1	319
100	Optical and Electrical Performance of SnO <sub>2</sub> Capped ZnO Nanowire Arrays. <i>Nano Letters</i> , 2007, 7, 3559-3563.	9.1	113
101	High-field electrical transport and breakdown behavior of double-walled carbon nanotube field-effect transistors. <i>Carbon</i> , 2007, 45, 760-765.	10.3	9
102	Establishing Ohmic contacts for in situ current-voltage characteristic measurements on a carbon nanotube inside the scanning electron microscope. <i>Nanotechnology</i> , 2006, 17, 1087-1098.	2.6	79
103	Near-Infrared Electrochromic and Electroluminescent Polymers Containing Pendant Ruthenium Complex Groups. <i>Macromolecules</i> , 2006, 39, 7502-7507.	4.8	67
104	Carbon nanotube as the core of conical carbon fiber: fabrication, characterization and field emission property. <i>Applied Physics A: Materials Science and Processing</i> , 2006, 86, 171-175.	2.3	13
105	Conical Carbon Fibers with Carbon Nanotubes as Their Cores: Fabrication, Characterization and Field Emission. , 2006, , .		0
106	Wetting and Contact Properties Studied Using the Nanoprobe System. <i>Materials Science Forum</i> , 2005, 475-479, 4081-4084.	0.3	0
107	Field-Effect Characteristics and Screening in Double-Walled Carbon Nanotube Field-Effect Transistors. <i>Journal of Physical Chemistry B</i> , 2005, 109, 17361-17365.	2.6	50
108	Formation energetics of n-member rings at the end of small zigzag carbon nanotubes. <i>Chemical Physics Letters</i> , 2002, 358, 103-109.	2.6	2

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109	High-mobility graphene on liquid p-block elements by ultra-low-loss CVD growth. , 0, .		1
110	Self-Reporting Activated Ester-Amine Reaction for Enantioselective Multi-Channel Visual Detection of Chiral Amines. <i>Angewandte Chemie</i> , 0, , .	2.0	10